# imall

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**Product data sheet** 

## **1. General description**

Planar passivated four quadrant triac in a SOT1292 (IITO3P) package intended for use in circuits where high static and dynamic dV/dt and high dI/dt can occur. This triac will commutate the full RMS current at the maximum rated junction temperature ( $T_{j(max)} = 150$  °C). It is used in applications where "high junction operating temperature capability" is required.

## 2. Features and benefits

- High current TRIAC
- Low thermal resistance
- High junction operating temperature capability (T<sub>i(max)</sub> = 150 °C)
- High voltage capability
- · Planar passivated for voltage ruggedness and reliability
- Insulated tab rated at 2500 V rms

## **3. Applications**

- High current / high surge applications
- · High power / industrial controls -- e.g. heating, motors, lighting

## 4. Quick reference data

#### Table 1. Quick reference data

Symbol	Parameter	Conditions	Values	Unit
Absolute	maximum rating			
$V_{\text{DRM}}$	repetitive peak off-state voltage		800	V
$I_{T(RMS)}$	RMS on-state current	full sine wave; T <sub>mb</sub> ≤ 105 °C; <u>Fig. 1; Fig. 2; Fig. 3</u>	40	A
I <sub>TSM</sub>	non-repetitive peak on- state current	full sine wave; $t_p = 20 \text{ ms}$ ; $T_{j(init)} = 25 \text{ °C}$ ; Fig. 4; Fig. 5	400	A
		full sine wave; $t_p$ = 16.7 ms; $T_{j(init)}$ = 25 °C;	440	А
Tj	junction temperature		150	°C

# BTA41-800B

4Q Triac

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static cha	racteristics	·				
I <sub>GT</sub>	gate trigger current	$V_{D} = 12 \text{ V}; I_{T} = 0.1 \text{ A}; \text{ T2+ G+} $ T <sub>j</sub> = 25 °C; <u>Fig. 7</u>	-	-	50	mA
		$V_{D} = 12 \text{ V}; I_{T} = 0.1 \text{ A}; \text{ T2+ G-} $ $T_{j} = 25 \text{ °C}; \text{ Fig. 7}$	-	-	50	mA
		$V_{D}$ = 12 V; I <sub>T</sub> = 0.1 A; T2- G- T <sub>j</sub> = 25 °C; <u>Fig. 7</u>	-	-	50	mA
		$V_{D}$ = 12 V; I <sub>T</sub> = 0.1 A; T2- G+ T <sub>j</sub> = 25 °C; <u>Fig. 7</u>	-	-	70	mA
I <sub>H</sub>	holding current	V <sub>D</sub> = 12 V; T <sub>j</sub> = 25 °C; <u>Fig. 9</u>	-	-	80	mA
V <sub>T</sub>	on-state voltage	I <sub>T</sub> = 56.6 A; T <sub>j</sub> = 25 °C; <u>Fig. 10</u>	-	1.2	1.5	V
Dynamic	characteristics					
dV <sub>D</sub> /dt	rate of rise of off-state voltage	$V_{DM}$ = 536 V; T <sub>j</sub> = 125 °C; (V <sub>DM</sub> = 67% of V <sub>DRM</sub> ); exponential waveform; gate open circuit	750	-	-	V/µs
		$V_{DM}$ = 536 V; T <sub>j</sub> = 150 °C; (V <sub>DM</sub> = 67% of V <sub>DRM</sub> ); exponential waveform; gate open circuit	500	-	-	V/µs
dl <sub>com</sub> /dt	rate of change of commutating current	$V_D = 400 \text{ V}; \text{ T}_j = 125 \text{ °C}; \text{ I}_{T(RMS)} = 20\text{ A};$ $dV_{com}/dt = 20 \text{ V}/\mu\text{s}; \text{ gate open circuit}$	20	-	-	A/ms
		$V_D$ = 400 V; T <sub>j</sub> = 150 °C; I <sub>T(RMS)</sub> = 20A; dV <sub>com</sub> /dt = 20 V/µs; gate open circuit	10	-	-	A/ms

# 5. Pinning information

Table 2. P	Table 2. Pinning information							
Pin	Symbol	Description	Simplified outline	Graphic symbol				
1	T1	main terminal 1	$\bigcirc$	T2T1				
2	T2	main terminal 2		G sym051				
3	G	gate		Symoor				
mb	n.c.	mounting base; isolated	IITO3P (SOT1292)					

# 6. Ordering information

#### Table 3. Ordering information

Type number	Package					
	Name	Description	Version			
BTA41-800B	IITO3P	plastic single-ended through-hole package; isolated heatsink mounted; 1 mounting hole; 3-lead TO3P	SOT1292			

# 7. Marking

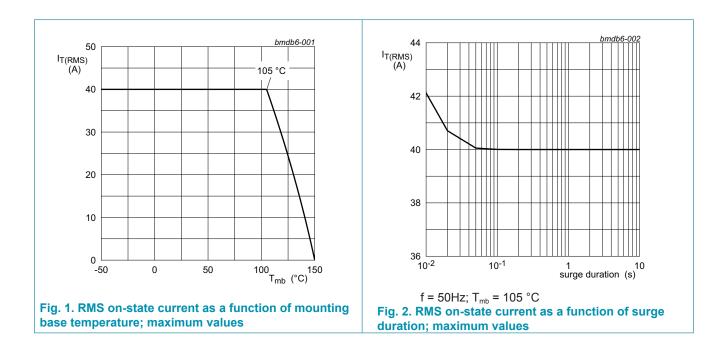
Table 4. Marking codes			
Type number		Marking codes	
BTA41-800B		BTA41-800B	
BTA41-800B	All information provided in this docume	nt is subject to legal disclaimers.	© WeEn Semiconductors Co., Ltd. 2017. All rights reserved
Product data sheet	10 July 201	7	2 / 12

## 8. Limiting values

#### Table 4. Limiting values

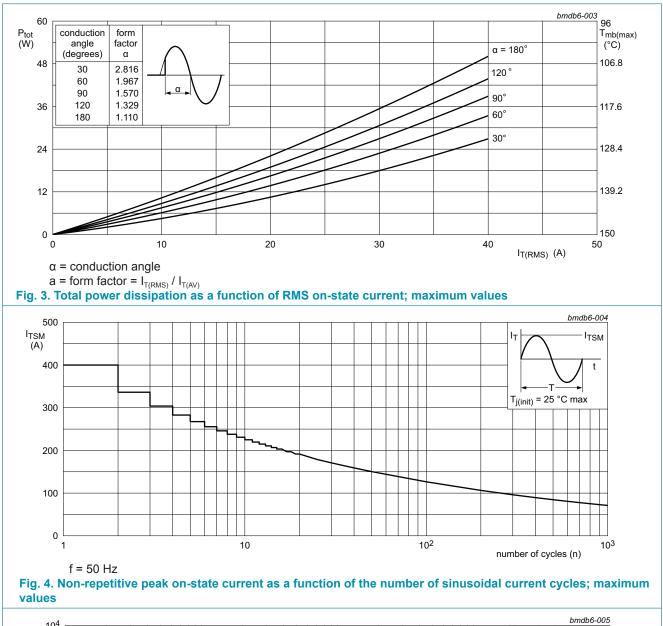
In accordance with the Absolute Maximum Rating System (IEC 60134).

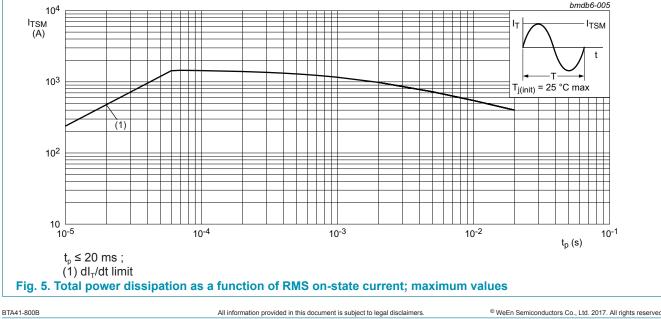
Symbol	Parameter	Conditions	Values	Unit
V <sub>DRM</sub>	repetitive peak off-state voltage		800	V
I <sub>T(RMS)</sub>	RMS on-state current	full sine wave; T <sub>mb</sub> ≤ 105°C; <u>Fig. 1</u> ; <u>Fig. 2; Fig. 3</u>	40	A
I <sub>TSM</sub>	non-repetitive peak on- state current	full sine wave; $t_p$ = 20 ms; $T_{j(init)}$ = 25 °C; Fig. 4; Fig. 5	400	A
		full sine wave; $t_p$ = 16.7 ms; $T_{j(init)}$ = 25 °C;	440	А
l <sup>2</sup> t	l <sup>2</sup> t for fusing	t <sub>p</sub> = 10ms; sine wave	800	A <sup>2</sup> s
dl⊤/dt	rate of rise of on-state current	I <sub>G</sub> = 150mA	150	A/µs
I <sub>GM</sub>	peak gate current	t <sub>p</sub> = 20µs	8	А
P <sub>GM</sub>	peak gate power	t <sub>p</sub> = 20µs	40	W
P <sub>G(AV)</sub>	average gate power	over any 20 ms period	1	W
T <sub>stg</sub>	storage temperature		-40 to 150	°C
T <sub>j</sub>	junction temperature		150	°C



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### **BTA41-800B 4Q Triac**





Unit

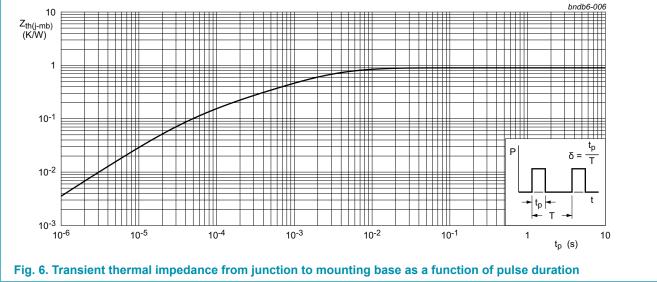
K/W

K/W

Table 5. Th	nermal characteristics								
Symbol	Parameter	Conditions		Min	Тур	Max			
$R_{th(j-mb)}$	thermal resistance from junction to mounting base	<u>Fig. 6</u>		-	-	0.9			
$R_{th(j-a)}$	thermal resistance from junction to	in free air		-	55	-			



ambient free air



# **10. Isolation characteristics**

Symbol	Plation characteristics Parameter	Conditions	Min	Тур	Max	Unit
$V_{\text{isol}(\text{RMS})}$	RMS isolation voltage	from all terminal to external heatsink; sinusoidal waveform; clean and dust free; 50 Hz $\leq$ f $\leq$ 60 Hz; RH $\leq$ 65 %; T <sub>h</sub> = 25 °C	-	-	2500	V

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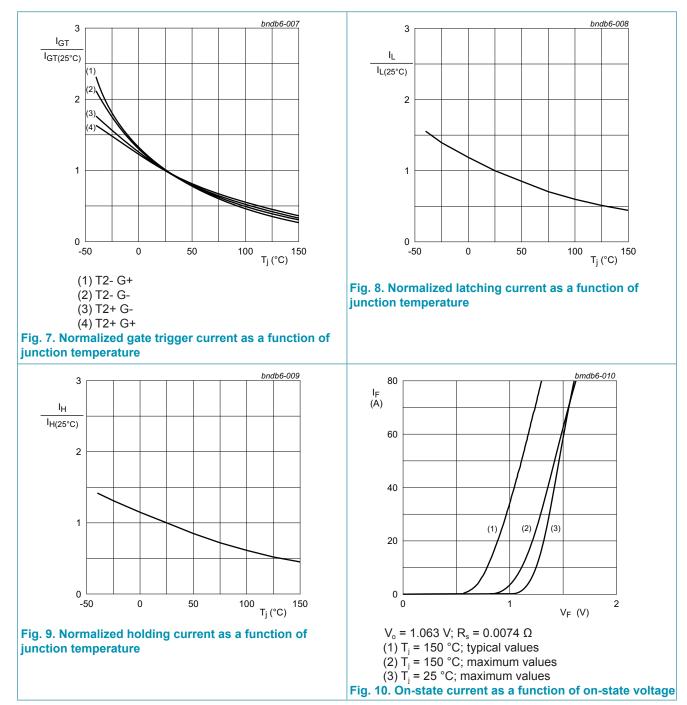
## **11. Characteristics**

	aracteristics					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static cha	racteristics					
I <sub>GT</sub>	gate trigger current	$V_{D} = 12 \text{ V}; \text{ I}_{T} = 0.1 \text{ A}; \text{ T2+ G+};$ $T_{j} = 25 \text{ °C}; \text{ Fig. 7}$	-	-	50	mA
		$V_D = 12 \text{ V}; \text{ I}_T = 0.1 \text{ A}; \text{ T2+ G-};$ $T_j = 25 \text{ °C}; \text{ Fig. 7}$	-	-	50	mA
		$V_D = 12 \text{ V}; \text{ I}_T = 0.1 \text{ A}; \text{ T2- G-};$ $T_j = 25 \text{ °C}; \text{ Fig. 7}$	-	-	50	mA
		$V_D = 12 \text{ V}; \text{ I}_T = 0.1 \text{ A}; \text{ T2- G+};$ $T_j = 25 \text{ °C}; \text{ Fig. 7}$	-	-	70	mA
IL	latching current	$V_D = 12 \text{ V}; \text{ I}_T = 0.1 \text{ A}; \text{ T2+ G+};$ $T_j = 25 \text{ °C}; \text{ Fig. 8}$	-	-	100	mA
		$V_D = 12 \text{ V}; \text{ I}_T = 0.1 \text{ A}; \text{ T2+ G-};$ $T_j = 25 \text{ °C}; \text{ Fig. 8}$	-	-	160	mA
		$V_D = 12 \text{ V}; \text{ I}_T = 0.1 \text{ A}; \text{ T2- G-};$ $T_j = 25 \text{ °C}; \text{ Fig. 8}$	-	-	100	mA
		$V_D = 12 \text{ V}; \text{ I}_T = 0.1 \text{ A}; \text{ T2- G+};$ $T_j = 25 \text{ °C}; \text{ Fig. 8}$	-	-	100	mA
I <sub>H</sub>	holding current	V <sub>D</sub> = 12 V; T <sub>j</sub> = 25 °C; <u>Fig. 9</u>	-	-	80	mA
V <sub>T</sub>	on-state voltage	I <sub>T</sub> = 56.6 A; T <sub>j</sub> = 25 °C; <u>Fig. 10</u>	-	1.2	1.5	V
V <sub>gt</sub>	gate trigger voltage	$V_{D} = 12 \text{ V}; \text{ I}_{T} = 0.1 \text{ A}; \text{ T}_{j} = 25 \text{ °C};$ Fig. 11	-	0.8	1.3	V
		$V_{D} = 400 \text{ V}; \text{ I}_{T} = 0.1 \text{ A}; \text{ T}_{j} = 150 \text{ °C};$ Fig. 11	0.2	0.45	-	V
I <sub>D</sub>	off-state current	$V_{\rm D}$ = 800 V; T <sub>j</sub> = 25 °C	-	-	10	μA
		V <sub>D</sub> = 800 V; T <sub>j</sub> = 150 °C	-	-	2.5	mA
Dynamic o	characteristics	· · · · ·	I			
dV <sub>D</sub> /dt	rate of rise of off-state voltage	$V_{DM}$ = 536 V; T <sub>j</sub> = 125 °C; (V <sub>DM</sub> = 67% of V <sub>DRM</sub> ); exponential waveform; gate open circuit	750	-	-	V/µs
		$V_{DM}$ = 536 V; T <sub>j</sub> = 150 °C; (V <sub>DM</sub> = 67% of V <sub>DRM</sub> ); exponential waveform; gate open circuit	500	-	-	V/µs
dI <sub>com</sub> /dt	rate of change of commutating current	$      V_{\rm D} = 400 \text{ V};  \text{T}_{\rm j} = 125 ^{\circ}\text{C};  \text{I}_{\text{T(RMS)}} = 20\text{A}; \\       dV_{\rm com}/dt = 20  \text{V/}\mu\text{s}; \text{ gate open circuit} $	20	-	-	A/ms
		$V_D = 400 \text{ V}; \text{ T}_j = 150 \text{ °C}; \text{ I}_{T(RMS)} = 20\text{ A};$ $dV_{com}/dt = 20 \text{ V}/\mu\text{s};$ gate open circuit	10	-	-	A/ms

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**BTA41-800B** 

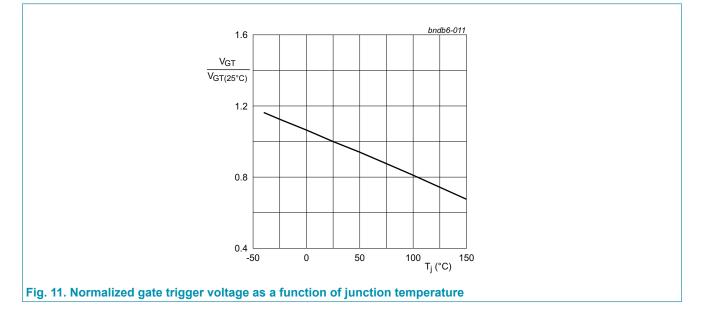
**4Q Triac** 



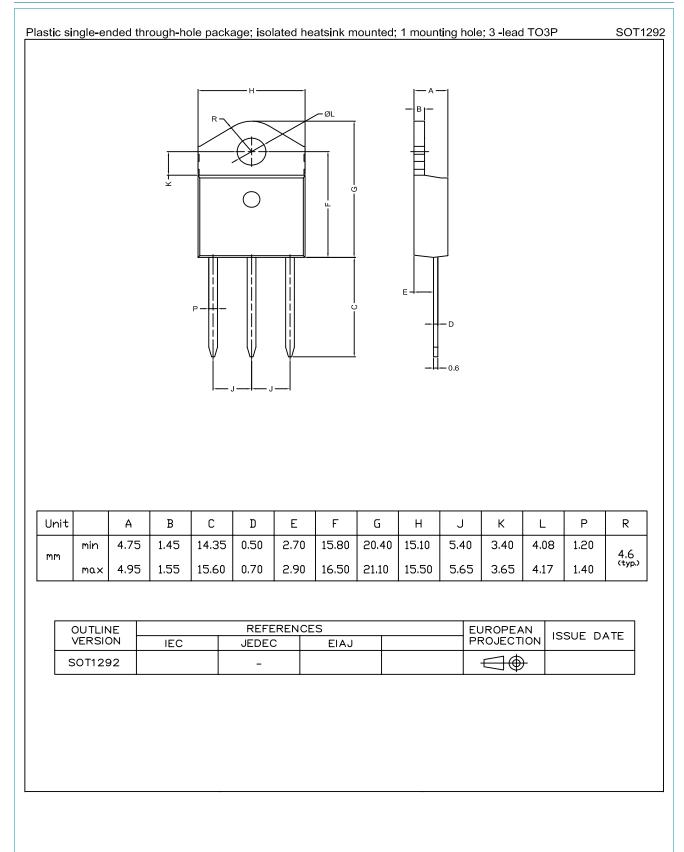
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BTA41-800B

4Q Triac



## 12. Package outline



## 13. Legal information

#### Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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